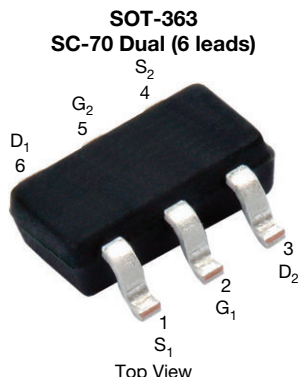


Automotive Dual N-Channel 20 V (D-S) 175 °C MOSFET



Marking Code: 8S

PRODUCT SUMMARY	
V_{DS} (V)	20
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V	0.350
$R_{DS(on)}$ (Ω) at $V_{GS} = 2.5$ V	0.600
I_D (A) per leg	0.84
Configuration	Dual
Package	SC-70

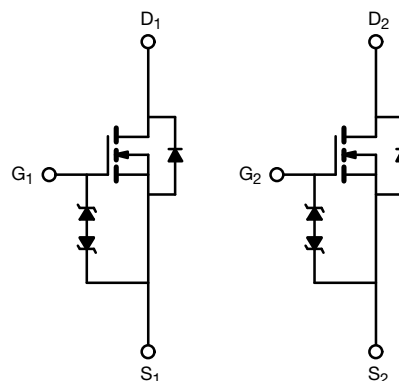
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g tested
- Typical ESD protection: 800 V
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912

AUTOMOTIVE
GRADE



RoHS
COMPLIANT
HALOGEN
FREE



ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	20	V
Gate-source voltage		V_{GS}	± 12	
Continuous drain current ^a	$T_C = 25$ °C	I_D	0.84	A
	$T_C = 125$ °C		0.49	
Continuous source current (diode conduction) ^a		I_S	0.54	
Pulsed drain current ^b		I_{DM}	3	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	3.3	
Single Pulse Avalanche Energy		E_{AV}	0.54	mJ
Maximum power dissipation ^b	$T_C = 25$ °C	P_D	1.5	W
	$T_C = 125$ °C		0.5	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R_{thJA}	460	°C/W
Junction-to-foot (drain)		R_{thJF}	350	

Notes

- Package limited
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		20	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		0.5	1	1.5	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 3 V		-	-	± 1	μA
		V _{DS} = 0 V, V _{GS} = ± 12 V		-	-	± 10	mA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 20 V	-	-	1	μA
		V _{GS} = 0 V	V _{DS} = 20 V, T _J = 125 °C	-	-	50	
		V _{GS} = 0 V	V _{DS} = 20 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 4.5 V	V _{DS} ≥ 5 V	0.4	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V	I _D = 0.4 A	-	0.200	0.350	Ω
		V _{GS} = 4.5 V	I _D = 0.4 A, T _J = 125 °C	-	-	0.507	
		V _{GS} = 4.5 V	I _D = 0.4 A, T _J = 175°C	-	-	0.600	
		V _{GS} = 2.5 V	I _D = 0.4 A	-	0.250	0.600	
Dynamic ^b							
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 10 V, f = 1 MHz	-	50	-	pF
Output capacitance	C _{oss}			-	21	-	
Reverse transfer capacitance	C _{rss}			-	10	-	
Total gate charge ^c	Q _g	V _{GS} = 4.5 V	V _{DS} = 10 V, I _D = 1.2 A	-	0.7	1.2	nC
Gate-source charge ^c	Q _{gs}			-	0.2	-	
Gate-drain charge ^c	Q _{gd}			-	0.2	-	
Gate resistance ^d	R _g	f = 1 MHz		4.5	9	13.7	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 10 V, R _L = 20 Ω I _D ≅ 0.5 A, V _{GEN} = 4.5 V, R _g = 1 Ω		-	10	15	ns
Rise time ^c	t _r			-	12	22	
Turn-off delay time ^c	t _{d(off)}			-	15	21	
Fall time ^c	t _f			-	6	10	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I _{SM}			-	-	3	A
Forward voltage	V _{SD}	I _F = 0.5 A, V _{GS} = 0		-	0.8	1.2	V

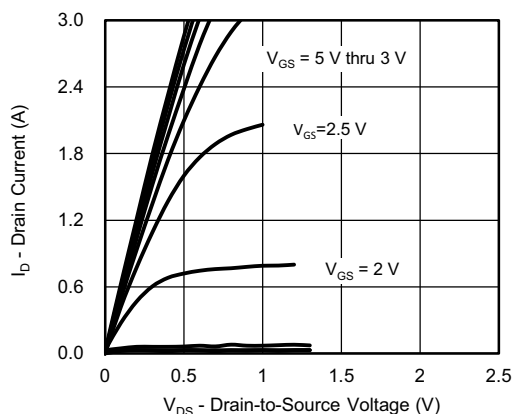
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature
d. Gate is obscured by ESD network series resistance and cannot be tested directly

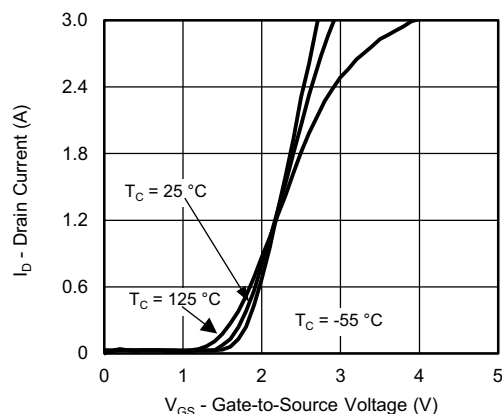
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



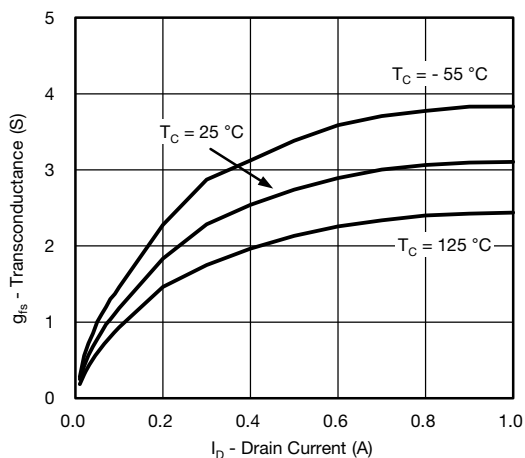
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



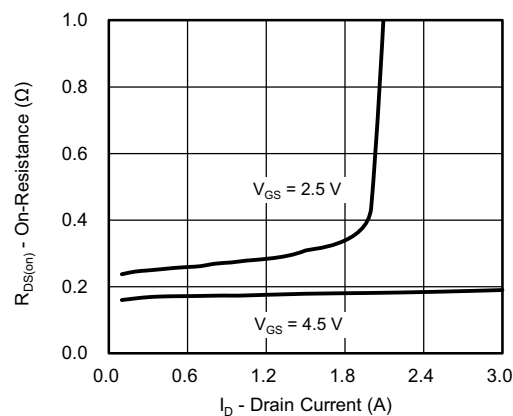
Output Characteristics



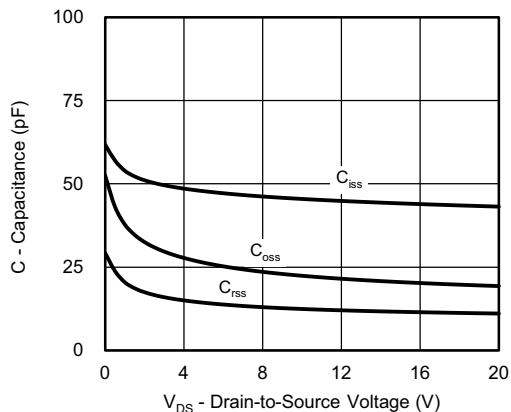
Transfer Characteristics



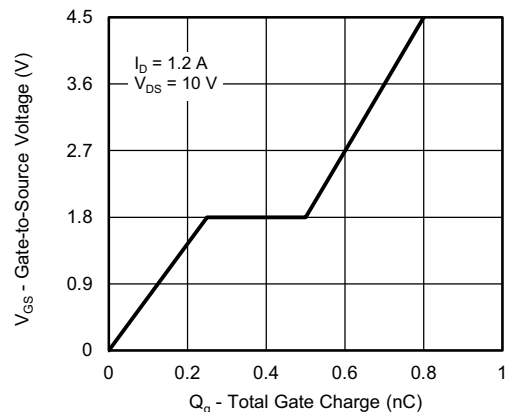
Transconductance



On-Resistance vs. Drain Current



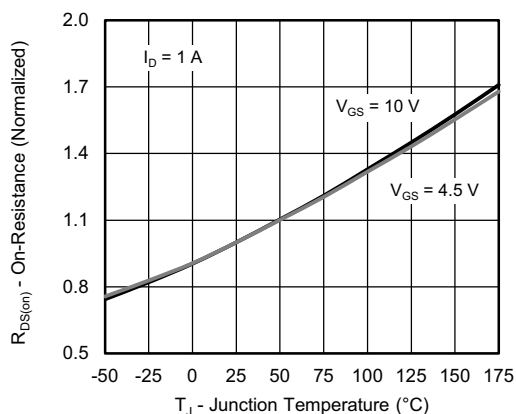
Capacitance



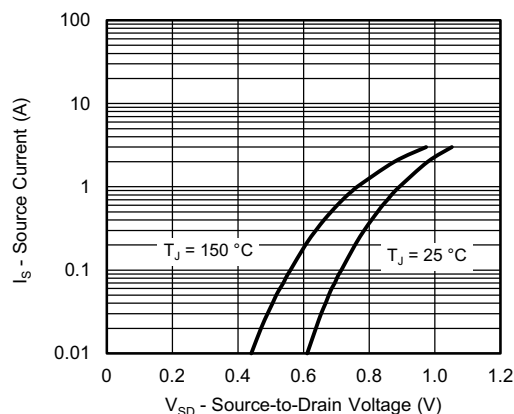
Gate Charge



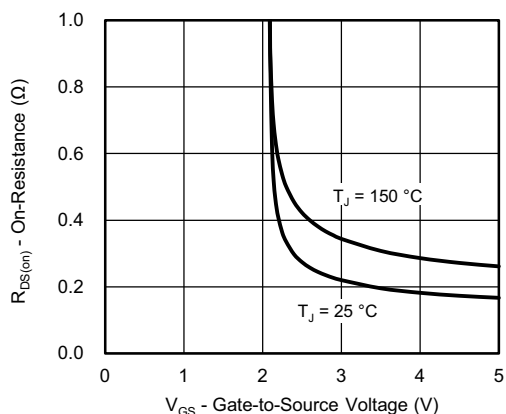
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



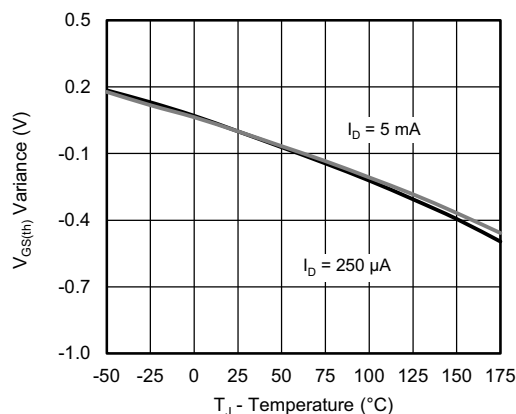
On-Resistance vs. Junction Temperature



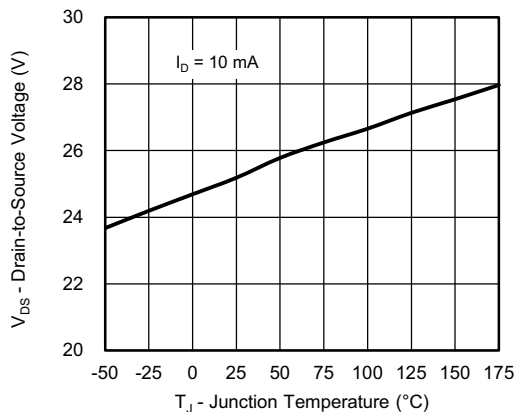
Source Drain Diode Forward Voltage



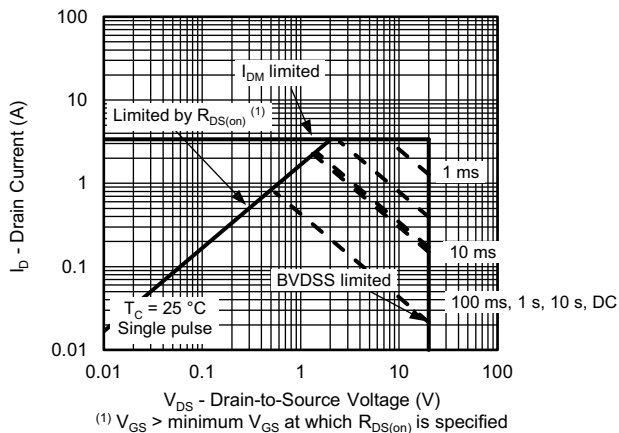
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



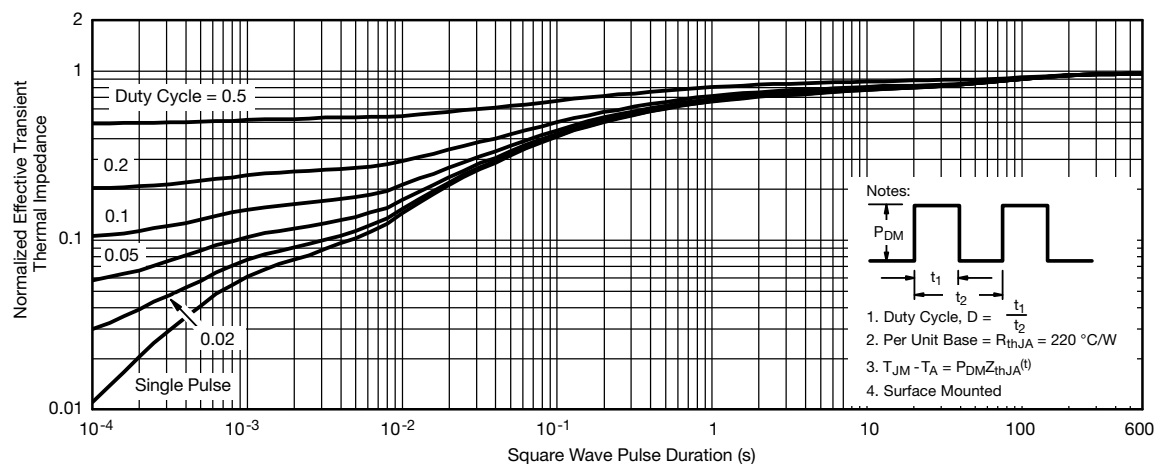
Drain Source Breakdown vs. Junction Temperature



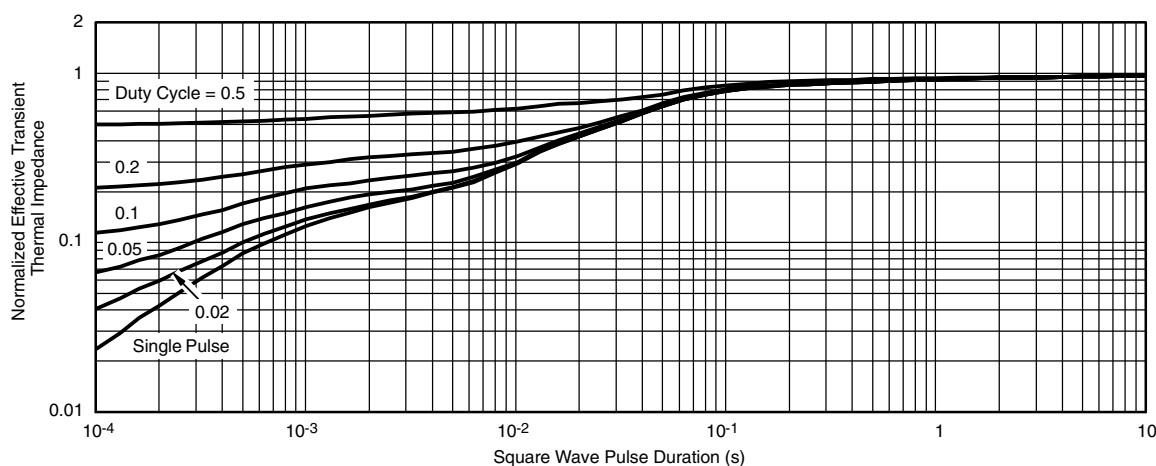
Safe Operating Area



THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

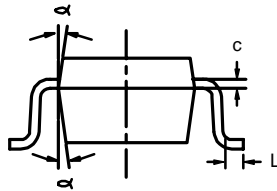
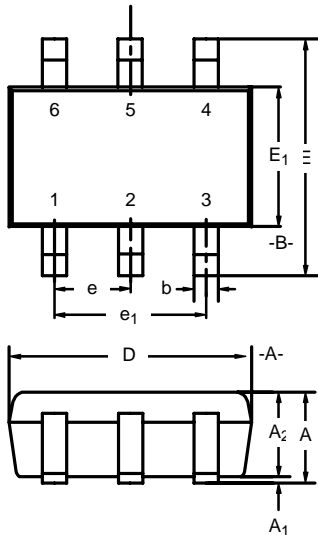
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^{\circ}\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^{\circ}\text{C}$)are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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SC-70: 6-LEADS

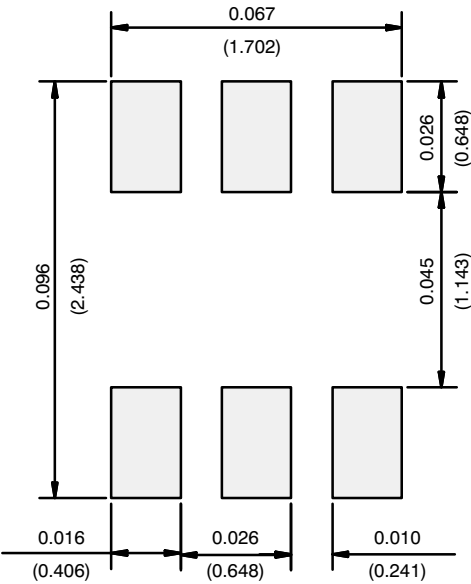


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.90	—	1.10	0.035	—	0.043
A ₁	—	—	0.10	—	—	0.004
A ₂	0.80	—	1.00	0.031	—	0.039
b	0.15	—	0.30	0.006	—	0.012
c	0.10	—	0.25	0.004	—	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65BSC			0.026BSC		
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
α	7°Nom			7°Nom		

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5550



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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